



PATENT APPLICATION  
Q-68381.

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Noureddine BOUADMA

Appln. No.: 10/066,641 ✓

Group Art Unit: 2828

Confirmation No.: 4521

Filed: February 6, 2002

Examiner: AL NAZER

For: BURIED RIBBON SEMICONDUCTOR LASER AND A METHOD OF FABRICATION

SECOND PROPOSED DRAWING CORRECTION

MAIL STOP NON-FEE

Commissioner for Patents

P.O. Box 1450

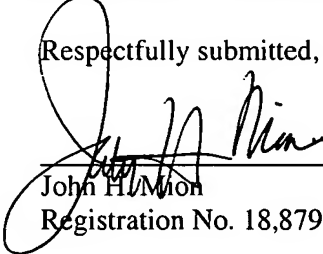
Alexandria, VA 22313-1450

Sir:

Further to the Proposed Drawing Correction filed on April 30, 2003, Applicant attaches copies of the drawing sheets containing Fig. 4 and Fig. 5 in which further (corrective) changes appear (in red ink). Specifically, "p-doped" is deleted from the legend for layer 21 in Fig. 4D, and "n-doped" is deleted from the legend for layer 20' in Fig. 5C".

It is requested that the Examiner approve these proposed corrections (along with those filed on April 30, 2003) so that the formal drawing can be corrected at the appropriate time.

Respectfully submitted,

  
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PATENT TRADEMARK OFFICE  
Date: May 21, 2003

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TC 2800 MAIL ROOM

10-6-03

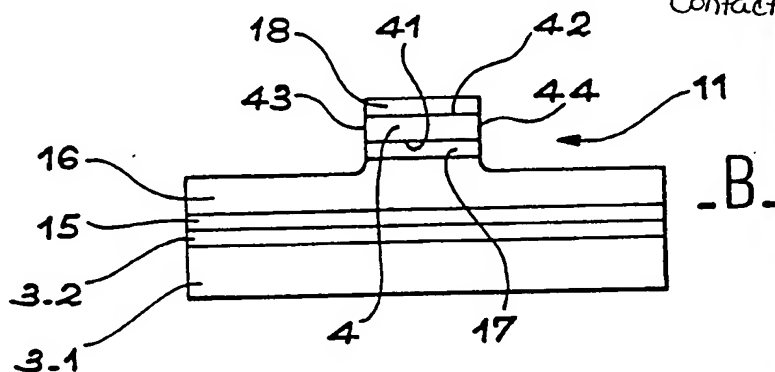
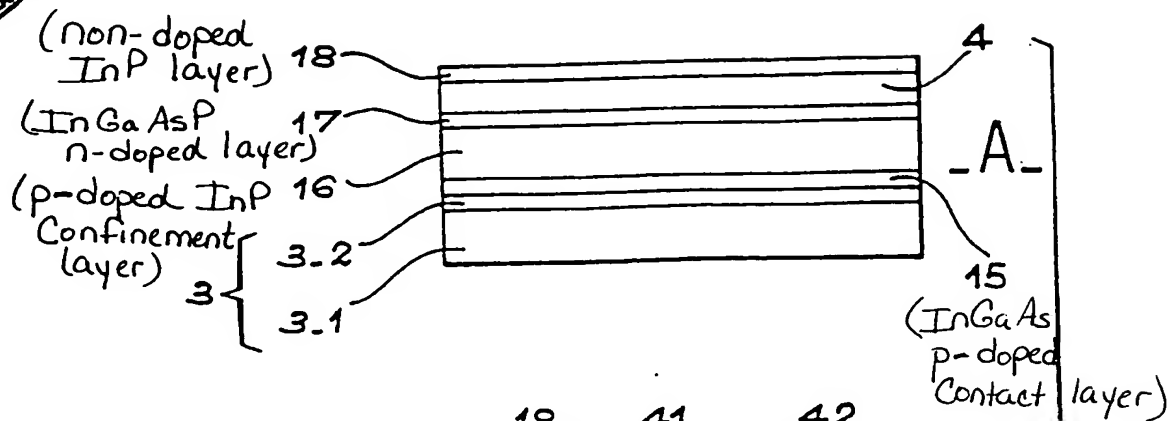
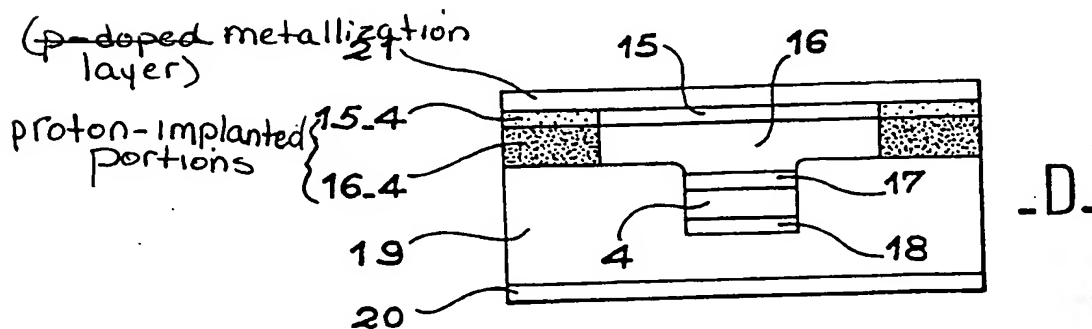
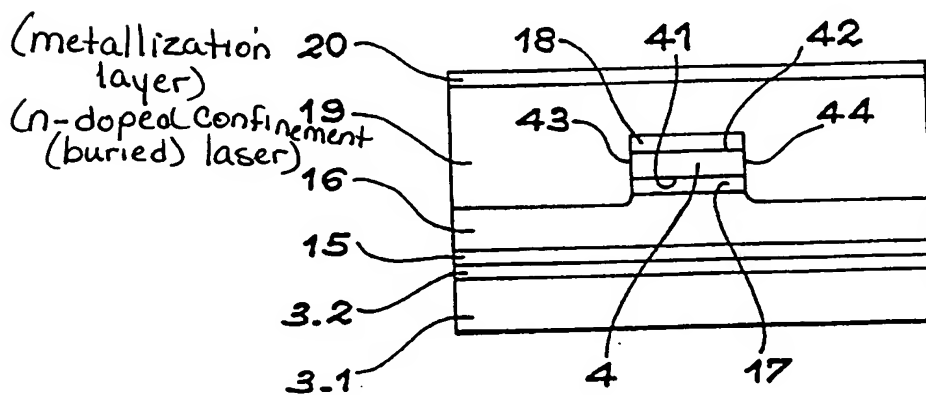


FIG. 4



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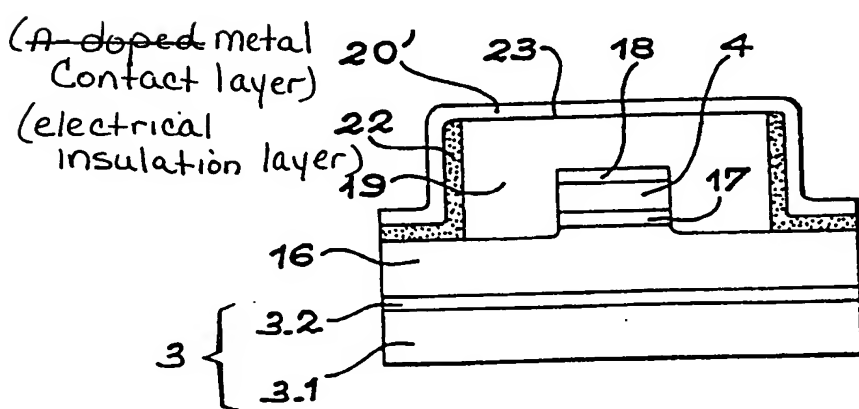
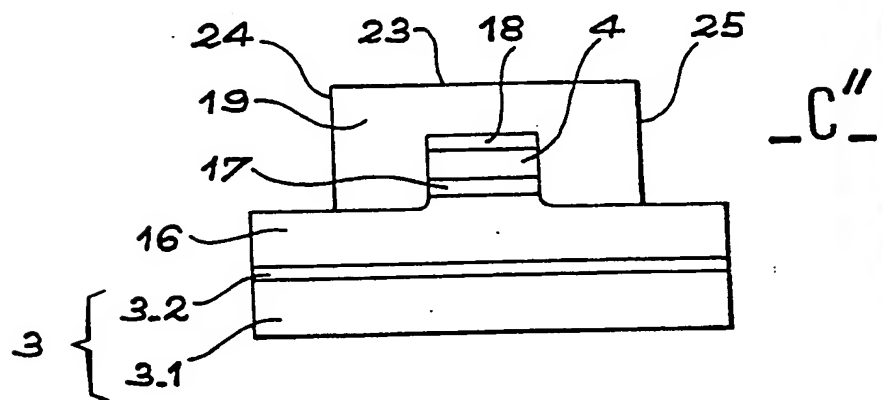
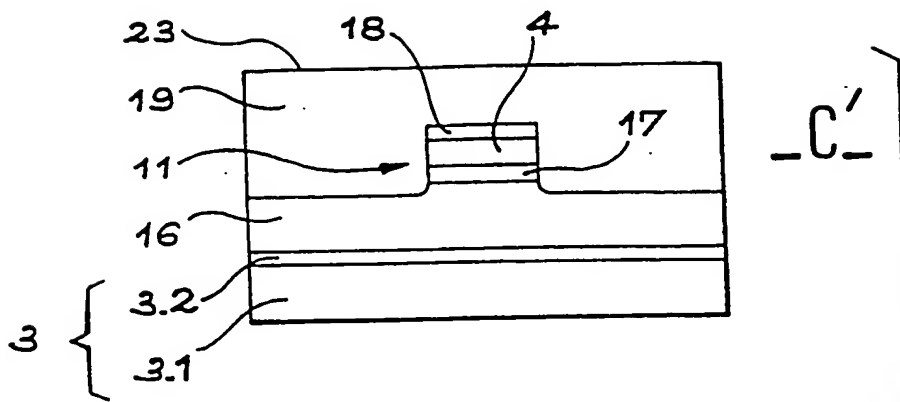


FIG. 5

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